2SA743, 2SA743A

Silicon PNP Epitaxial

HITACHI

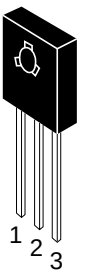
ADE-208-853 (Z)
1st. Edition
Sep. 2000

Application

Low frequency power amplifier complementary pair with 2SC1212 and 2SC1212A

Outline

TO-126 MOD



1. Emitter
2. Collector
3. Base

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings 2SA743	Ratings 2SA743A	Unit
Collector to base voltage	V_{CBO}	–50	–80	V
Collector to emitter voltage	V_{CEO}	–50	–80	V
Emitter to base voltage	V_{EBO}	–4	–4	V
Collector current	I_C	–1	–1	A
Collector power dissipation	P_C	0.75	0.75	W
	P_C*[1]	8	8	
Junction temperature	Tj	150	150	°C
Storage temperature	Tstg	–55 to +150	–55 to +150	°C

Note: 1. Value at T_C = 25°C.

Hitachi semiconductor

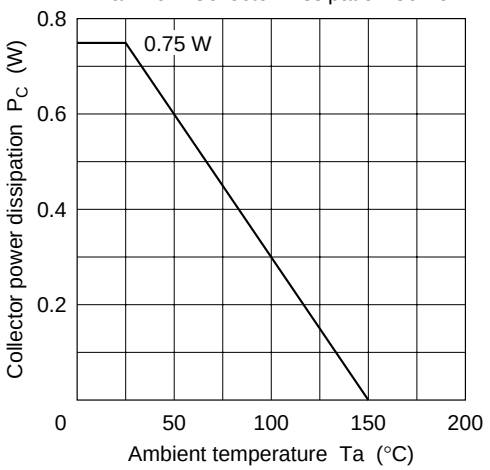
Electrical Characteristics (Ta = 25°C)

Item	Symbol	2SA743 Min	2SA743 Typ	2SA743 Max	2SA743A Min	2SA743A Typ	2SA743A Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	–50	—	—	–80	—	—	V	I_C = –1 mA, I_E = 0
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	–50	—	—	–80	—	—	V	I_C = –10 mA, R_{BE} = ∞
Emitter to base breakdown voltage	$V_{(BR)EBO}$	–4	—	—	–4	—	—	V	I_E = –1 mA, I_C = 0
Collector cutoff current	I_{CER}	—	—	–20	—	—	—	µA	V_{CE} = –50 V, R_{BE} = 1 kΩ
	I_{CER}	—	—	—	—	—	–20		V_{CE} = –80 V, R_{BE} = 1 kΩ
DC current tarnsfer ratio	h_{FE}*[1]	60	120	200	60	120	200		V_{CE} = –4 V, I_C = –50 mA
	h_{FE}	20	—	—	20	—	—		V_{CE} = –4 V, I_C = –1 A (pulse)
Base to emitter voltage	V_{BE}	—	–0.65	–1.0	—	–0.65	1.0	V	V_{CE} = –4 V, I_C = –50 mA
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	–0.75	–1.5	—	–0.75	–1.5	V	I_C = –1 A, I_B = –0.1 A
Gain bandwidth product	f_T	—	120	—	—	120	—	MHz	V_{CE} = –4 V, I_C = –30 mA

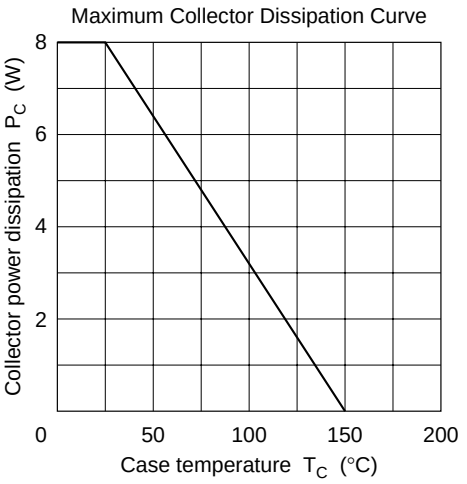
Note: 1. The 2SA743 and 2SA743A is grouped by h_{FE} as follows.

B	C
60 to 120	100 to 200

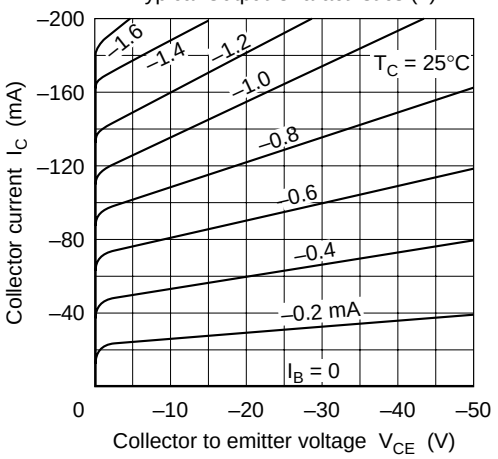
Maximum Collector Dissipation Curve



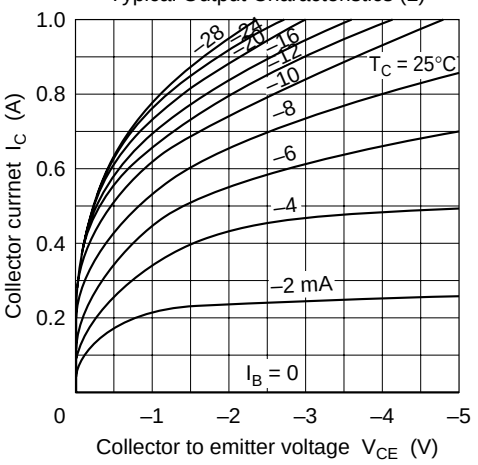
Maximum Collector Dissipation Curve



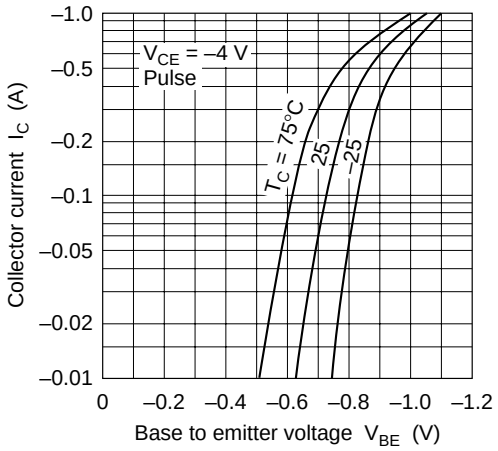
Typical Output Charactristics (1)



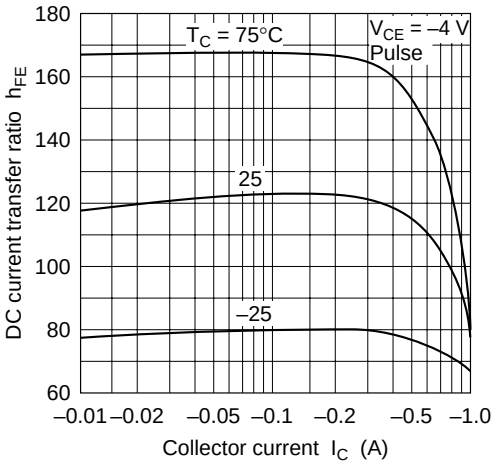
Typical Output Characteristics (2)



Typical Transfer Characteristics



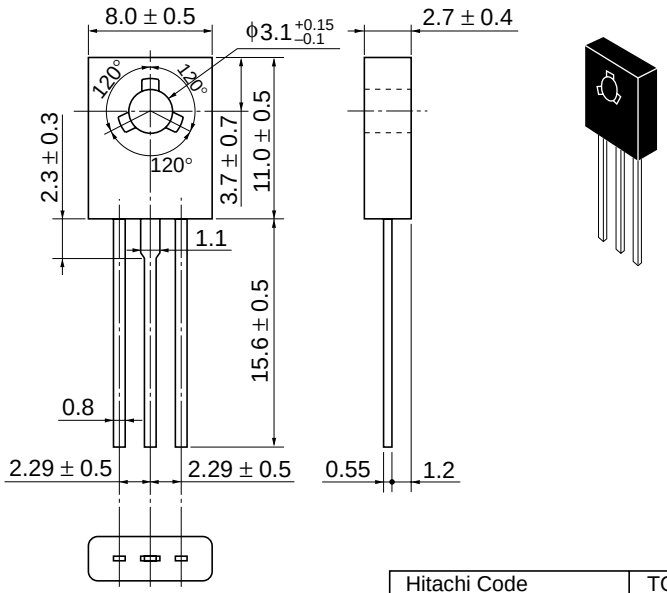
DC Currnet Transfer Ratio vs. Collector Current



Package Dimensions

Package Dimensions

Unit: mm



Hitachi Code	TO-126 Mod
JEDEC	—
EIAJ	—
Mass (reference value)	0.67 g

Cautions

1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
5. This product is not designed to be radiation resistant.
6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

HITACHI

Hitachi, Ltd.
Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL
NorthAmerica : http://semiconductor.hitachi.com/
Europe : http://www.hitachi-eu.com/hel/ecg
Asia : http://sicapac.hitachi-asia.com
Japan : http://www.hitachi.co.jp/Sicd/indx.htm

For further information write to:

Hitachi Semiconductor (America) Inc.
179 East Tasman Drive,
San Jose,CA 95134
Tel: <1> (408) 433-1990
Fax: <1>(408) 433-0223

Hitachi Europe GmbH
Electronic Components Group
Dornacher Straβe 3
D-85622 Feldkirchen, Munich
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.
Electronic Components Group.
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 585160

Hitachi Asia Ltd.
Hitachi Tower
16 Collyer Quay #20-00,
Singapore 049318
Tel : <65>-538-6533/538-8577
Fax : <65>-538-6933/538-3877
URL : http://www.hitachi.com.sg

Hitachi Asia Ltd.
(Taipei Branch Office)
4/F, No. 167, Tun Hwa North Road,
Hung-Kuo Building,
Taipei (105), Taiwan
Tel : <886>-(2)-2718-3666
Fax : <886>-(2)-2718-8180
Telex : 23222 HAS-TP
URL : http://www.hitachi.com.tw

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower,
World Finance Centre,
Harbour City, Canton Road
Tsim Sha Tsui, Kowloon,
Hong Kong
Tel : <852>-(2)-735-9218
Fax : <852>-(2)-730-0281
URL : http://www.hitachi.com.hk

Colophon 2.0